Fundamental phenomena and applications of exciton-polariton condensates (II)

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Outline

1. Motivations

2. Samples



Outline

1. Motivations

2. Samples

3. Devices



Outline

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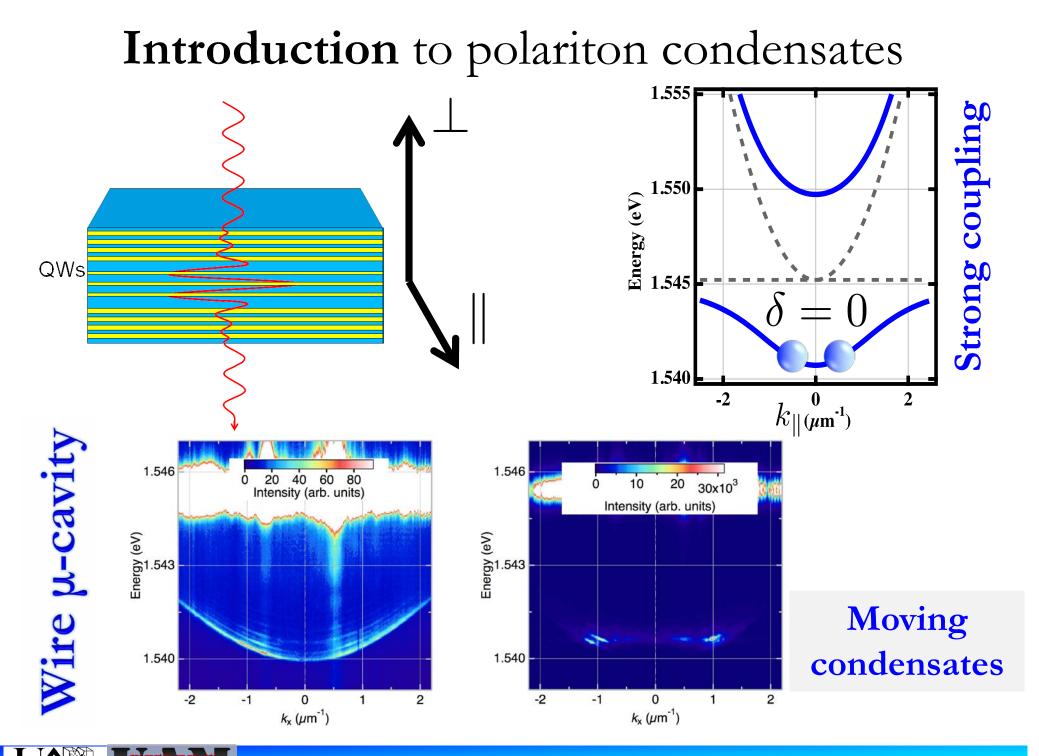
1. Motivations

2. Samples

3. Devices

4. Coherence in k-space

5. Summary



New Frontiers in 2D materials: Approaches & Applications

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On the polaritronic technology...

Bose-Einstein condensates as a tool for technological development

✓ Coherence

$$\Psi_{0}\left(r,t
ight)$$

- ✓ Superfluid character
- \checkmark Spin properties



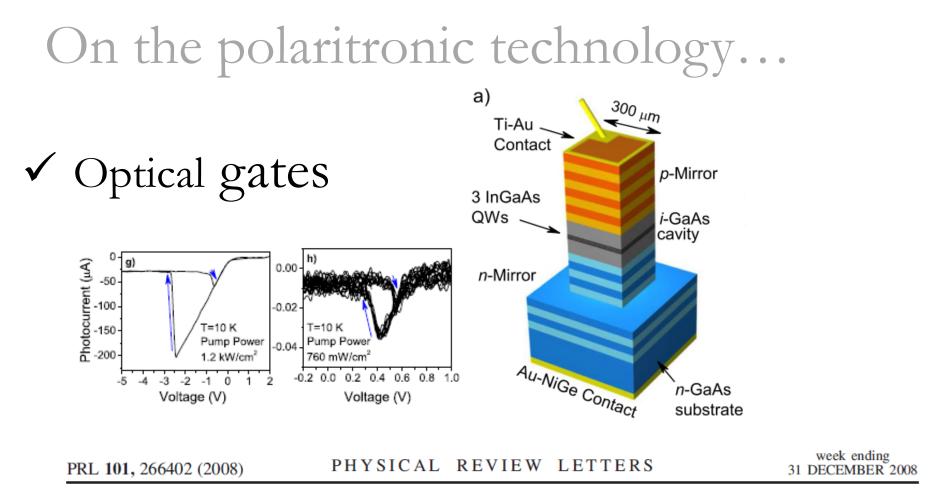


Why use polaritons?

species	atomic gases	polaritons
mass m^*/m_0	10^{4}	10^{-5}
Bohr radius	$10^{-1}{ m \AA}$	10^2\AA
λ_T at T_c	10^{3} Å	10^4 Å
T_c	$< 1 \mu K$	$10-300 \mathrm{K}$



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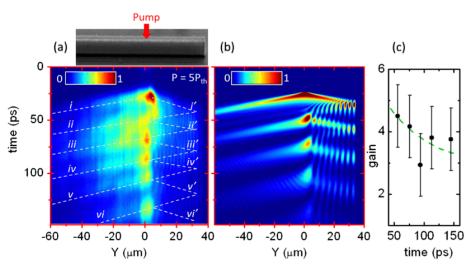
Optical Bistability in a GaAs-Based Polariton Diode

Daniele Bajoni,* Elizaveta Semenova, Aristide Lemaître, Sophie Bouchoule, Esther Wertz, Pascale Senellart, Sylvain Barbay, Robert Kuszelewicz, and Jacqueline Bloch[†]

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On the polaritronic technology...

✓ Optical amplifiers

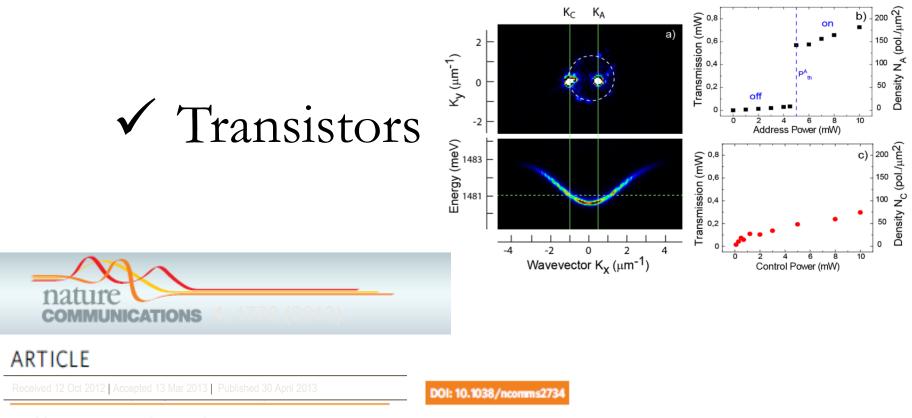




Propagation and Amplification Dynamics of 1D Polariton Condensates

E. Wertz,¹ A. Amo,¹ D. D. Solnyshkov,² L. Ferrier,¹ T. C. H. Liew,³ D. Sanvitto,^{4,5} P. Senellart,¹ I. Sagnes,¹ A. Lemaître,¹ A. V. Kavokin,^{6,7} G. Malpuech,² and J. Bloch^{1,*}

On the polaritronic technology...



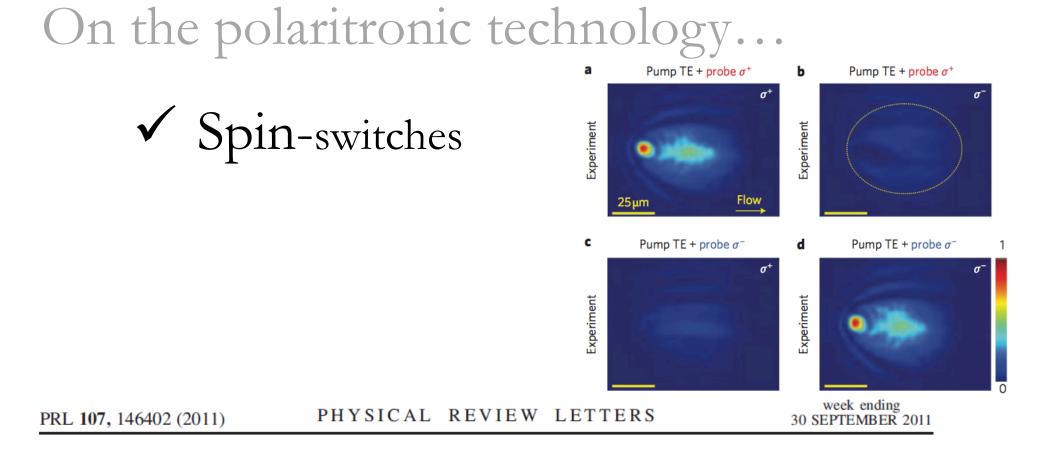
All-optical polariton transistor

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D. Ballarini^{1,2}, M. De Giorgi^{1,2}, E. Cancellieri^{3,4}, R. Houdré⁵, E. Giacobino⁴, R. Cingolani¹, A. Bramati⁴, G. Gigli^{1,2,6} & D. Sanvitto^{1,2}

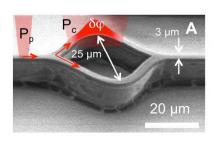
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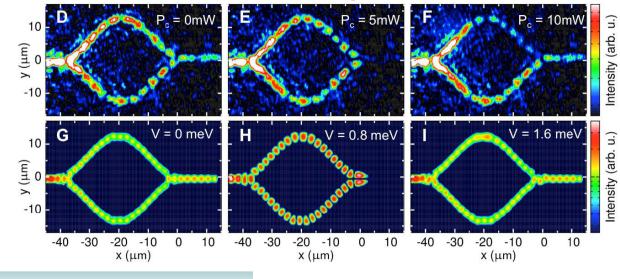


Motion of Spin Polariton Bullets in Semiconductor Microcavities

C. Adrados,¹ T.C. H. Liew,² A. Amo,^{1,3} M. D. Martín,⁴ D. Sanvitto,^{4,5} C. Antón,⁴ E. Giacobino,¹ A. Kavokin,^{6,7} A. Bramati,¹ and L. Viña⁴

On the polaritronic technology... ✓ Circuits







ARTICLE

Received 7 May 2013 | Accepted 17 Jan 2014 | Published 11 Feb 2014

DOI: 10.1038/ncomms4278 OPEN

All-optical phase modulation in a cavity-polariton Mach-Zehnder interferometer

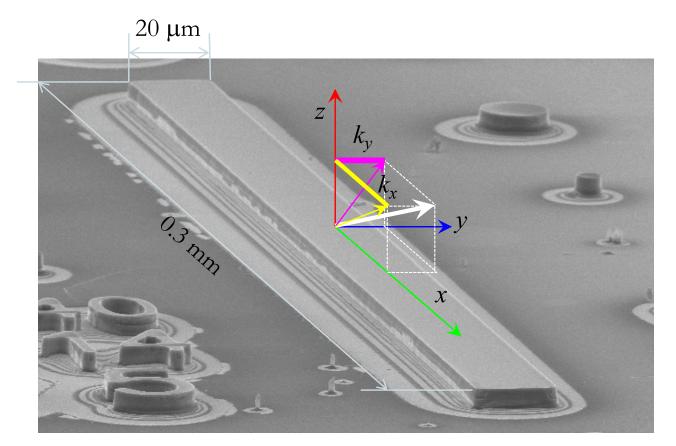
C. Sturm^{1,2,*}, D. Tanese^{1,*}, H.S. Nguyen¹, H. Flayac³, E. Galopin¹, A. Lemaître¹, I. Sagnes¹, D. Solnyshkov³, A. Amo¹, G. Malpuech³ & J. Bloch¹





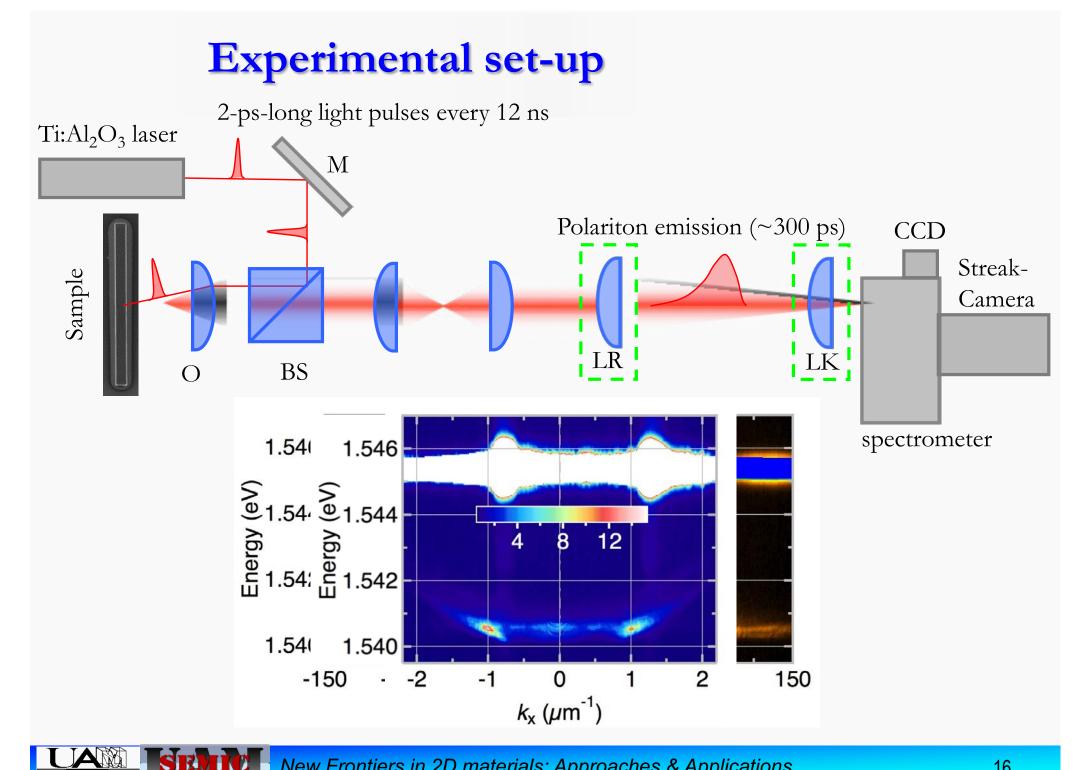


Description of the samples



high-quality AlGaAs-based microcavities

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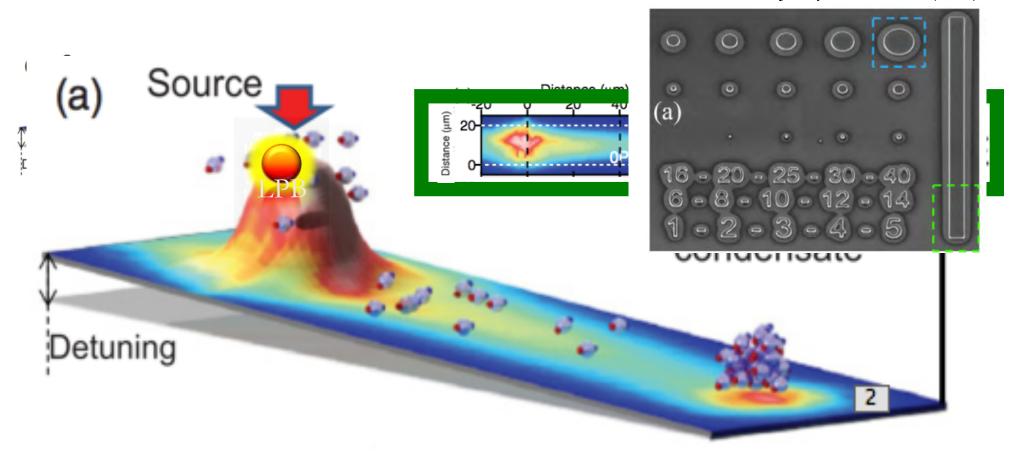


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Original work on transistor switch

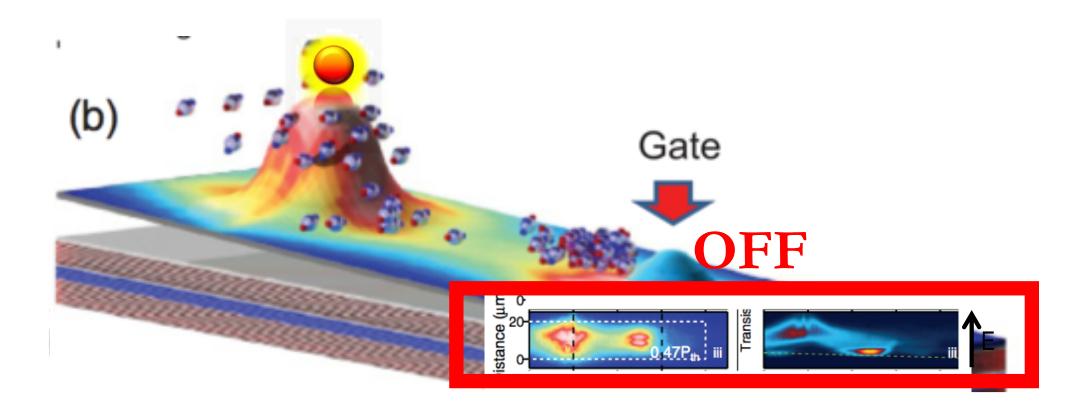
P Tsotsis et al, New J. Phys. 14, 023060 (2012)



T. Gao, et. al., "Polariton condensate transistor switch", Phys. Rev. B 85, 235102 (2012).



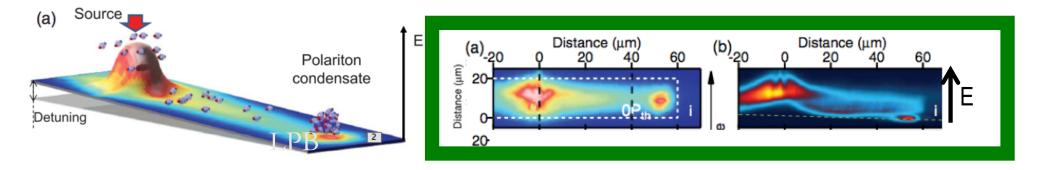
Original work on transistor switch



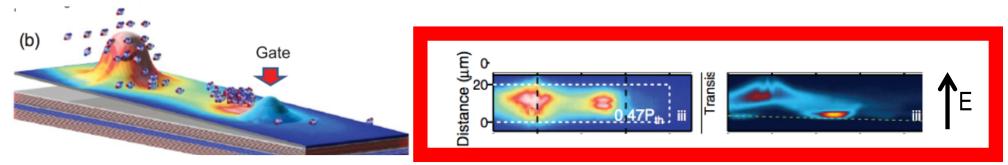
T. Gao, et. al., "Polariton condensate transistor switch", Phys. Rev. B 85, 235102 (2012).



Original work on transistor switch ON







T. Gao, et. al., "Polariton condensate transistor switch", Phys. Rev. B 85, 235102 (2012).



3. Devices

Transistor switch

T. Gao, et. al., "Polariton condensate transistor switch", Phys. Rev. B 85, 235102 (2012).

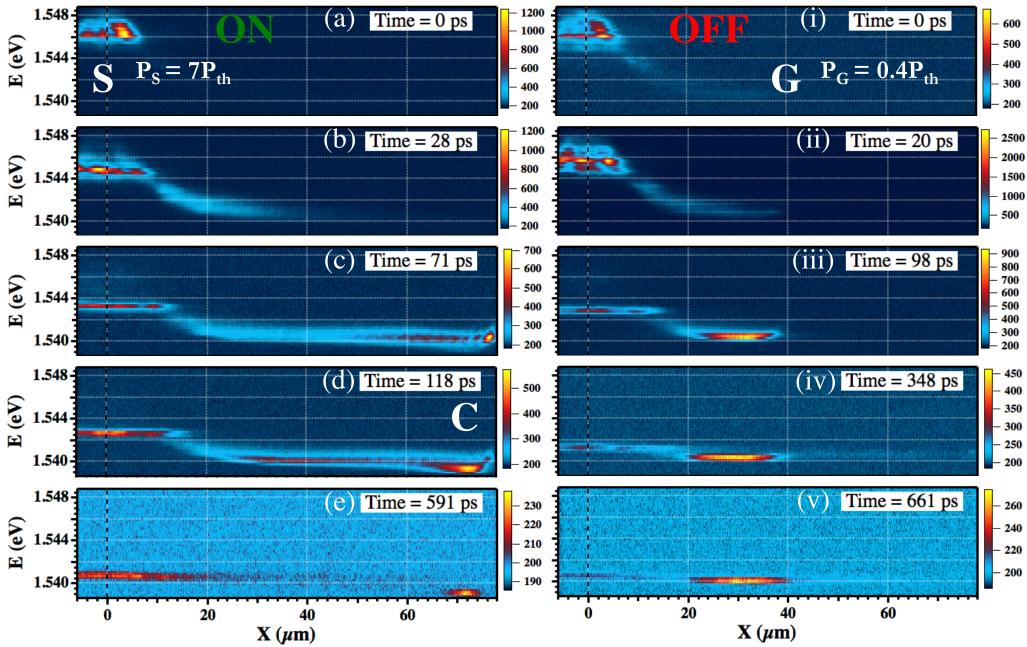
C. Anton, et. al., "Dynamics of a polariton condensate transistor switch", App. Phys. Lett. 101, 261116 (2012).

C. Anton, et. al., "Energy relaxation of exciton-polariton condensates in quasi-1D microcavities", Phys. Rev. B 88, 035313 (2013).

C. Anton, et. al., "Quantum reflections and shunting of polariton condensate wave trains...", Phys. Rev. B 88, 245307 (2013).

C. Anton, et. al., "Operation speed of polariton condensate switches gated by excitons", Phys. Rev. B 89, 235312 (2014).

Experiments on transistor switch

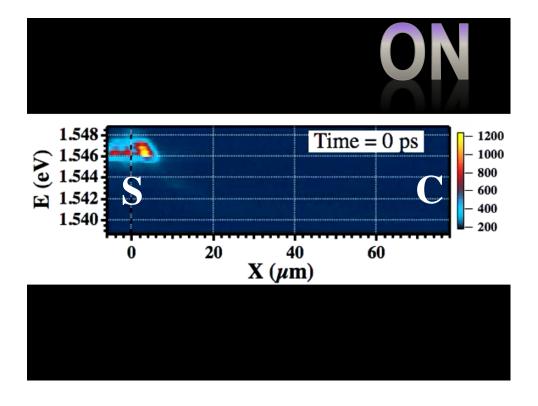


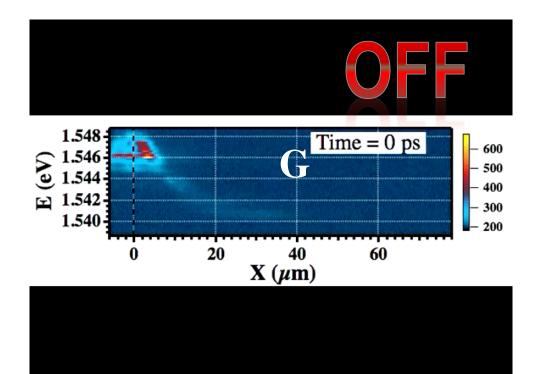
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SEM

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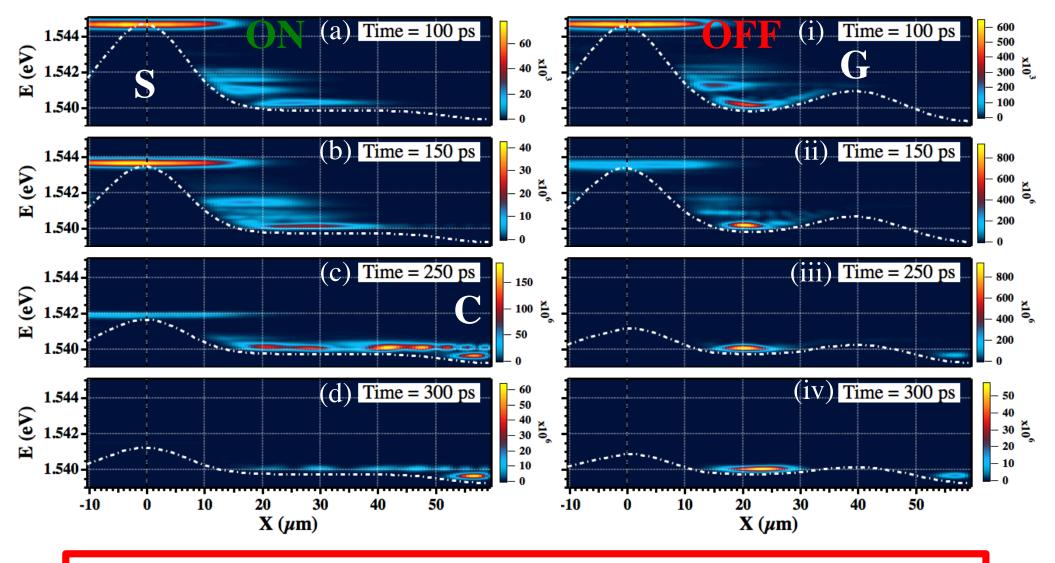
Experiments on transistor switch







Simulations - Gross-Pitaevskii Equation

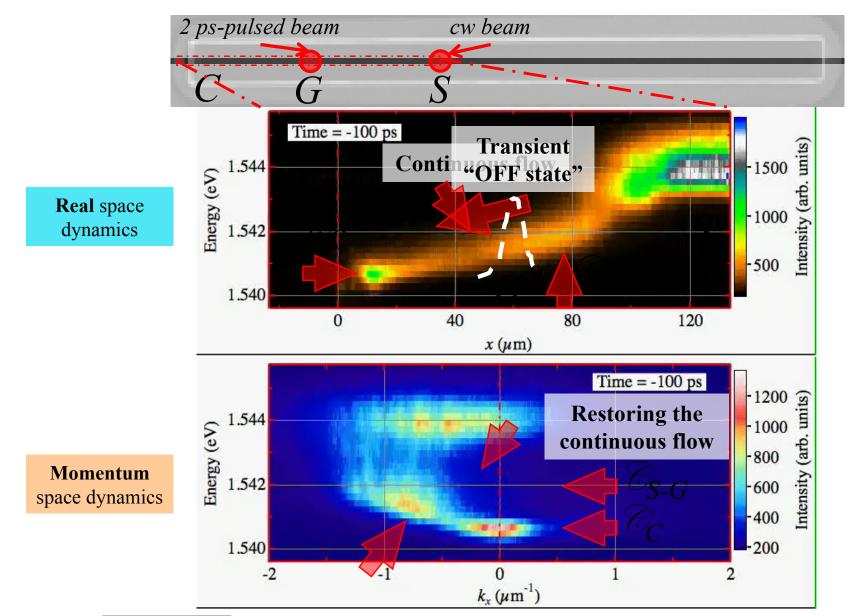


By... T.C.H. Liew, School of Physical and Mathematical Sciences, Nanyang Technological University, Singapore

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How fast can it work?: Operation speed between the ON-OFF-ON states

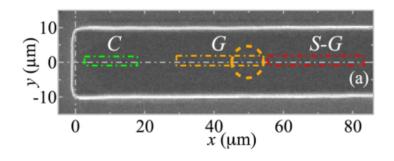


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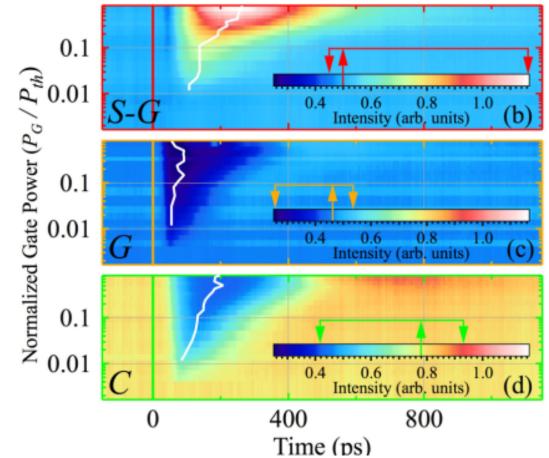
Operation speed of the device with excitonic gates

Gate pump power dependence on the operation speed the device



SEM

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Operation speed of the device with excitonic gates

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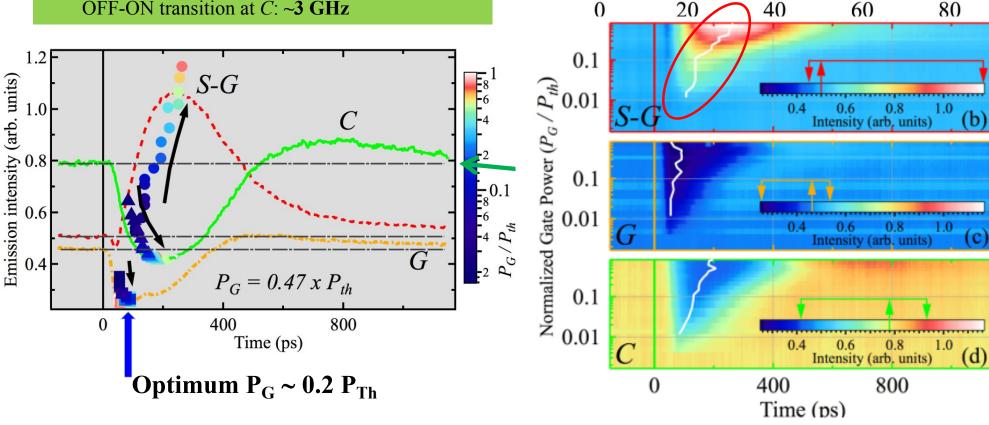
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Gate pump power dependence on the operation speed the device

Maximizing the ON/OFF ratio at *C*: ~30%

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Minimizing the temporal interval of the ON- \checkmark OFF-ON transition at *C*: ~3 GHz

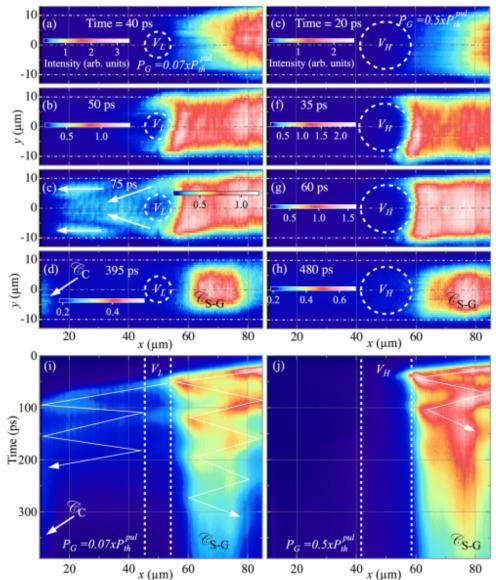


S-G

(a)

b

Leakage effects

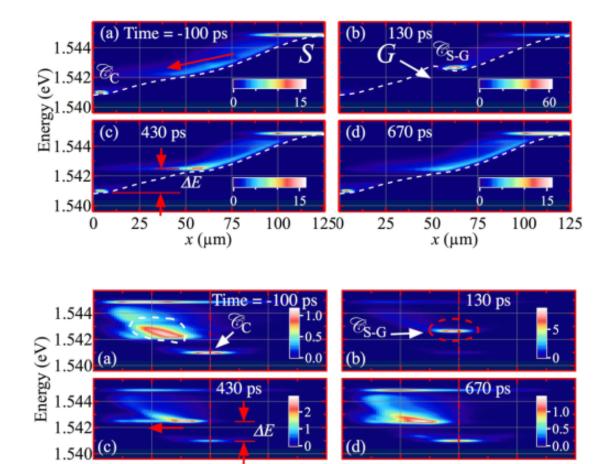




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Simulations - Gross-Pitaevskii Equation



By... T.C.H. Liew, School of Physical and Mathematical Sciences, Nanyang Technological University, Singapore

2 - 2

 $k_x (\mu m^{-1})$

1

2

-1

 $k_{x} (\mu m^{-1})$

1

-1

-2

SEN

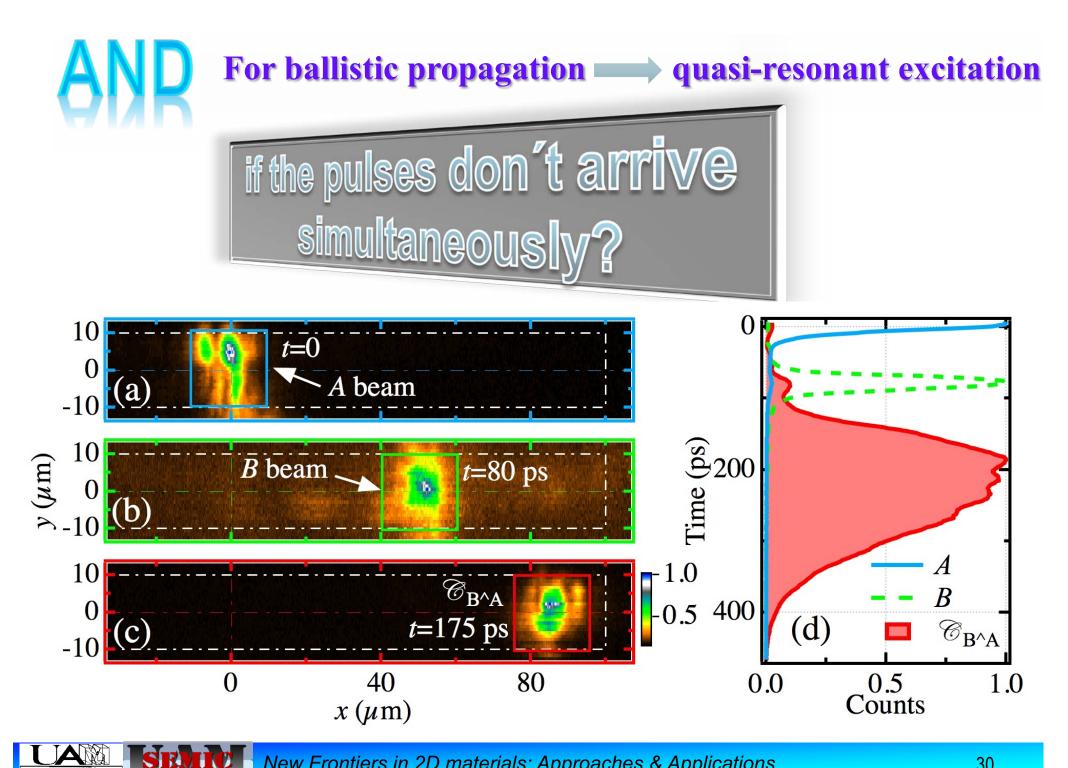
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4. Experimental results time-resolved (dynamics)

AND logic gate

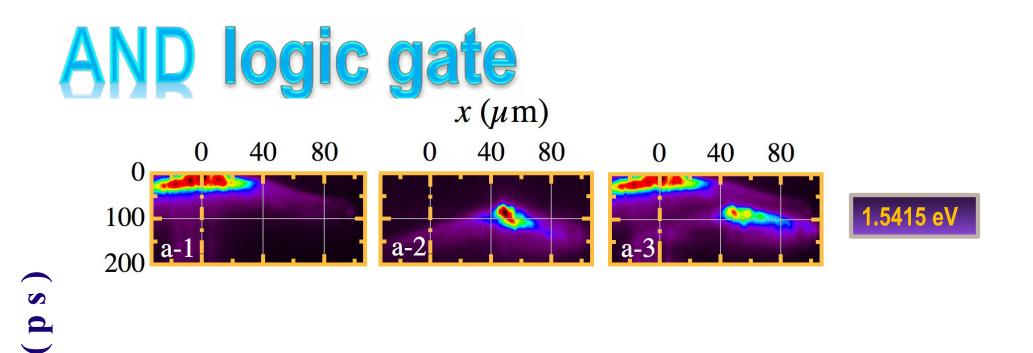
PHYSICAL REVIEW B 88, 245307 (2013)

Quantum reflections and shunting of polariton condensate wave trains: Implementation of a logic AND gate



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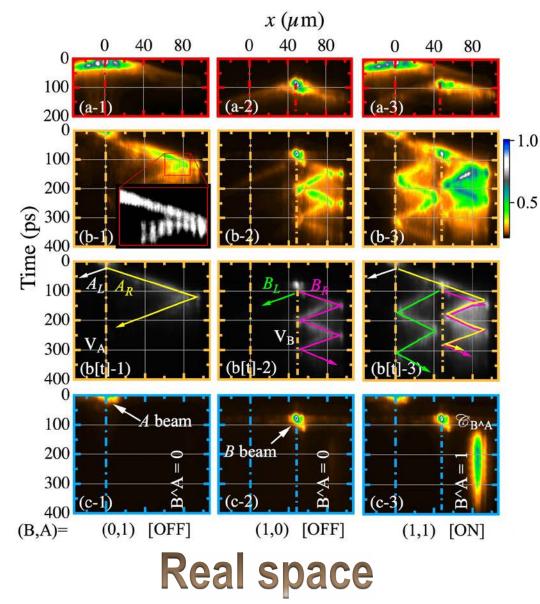
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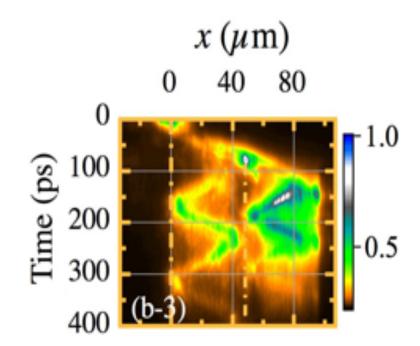
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AND logic gate



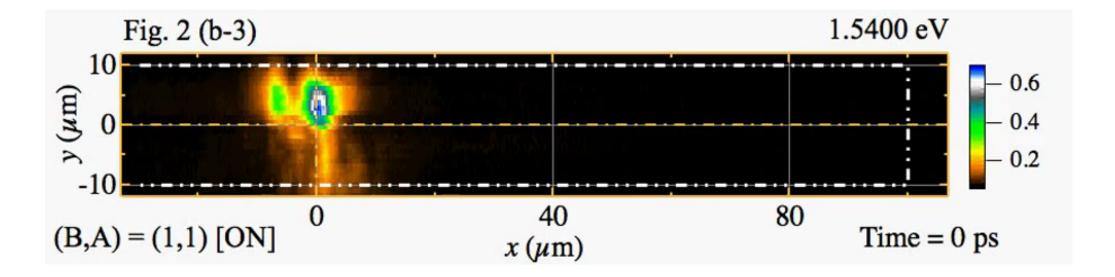
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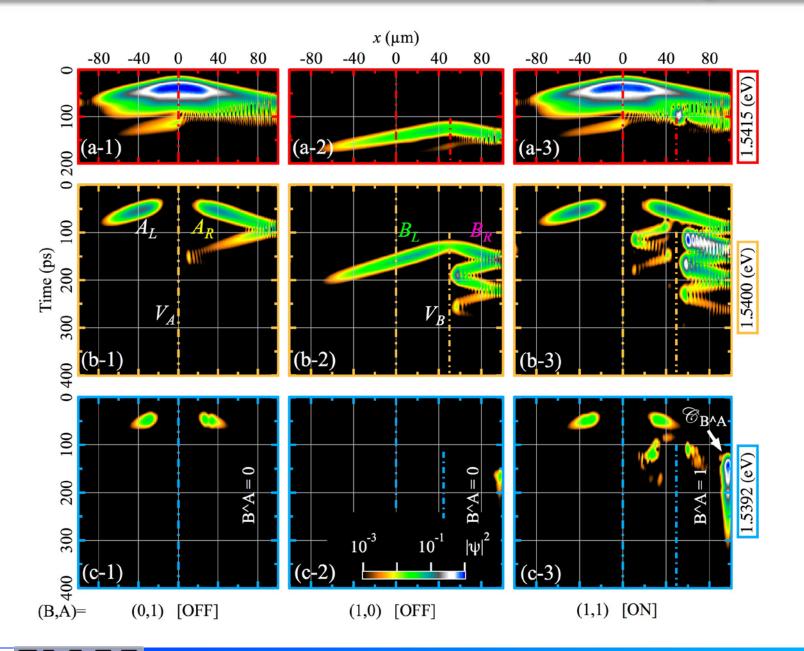


ANR logic gate





Simulations - Gross–Pitaevskii Equation



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SE

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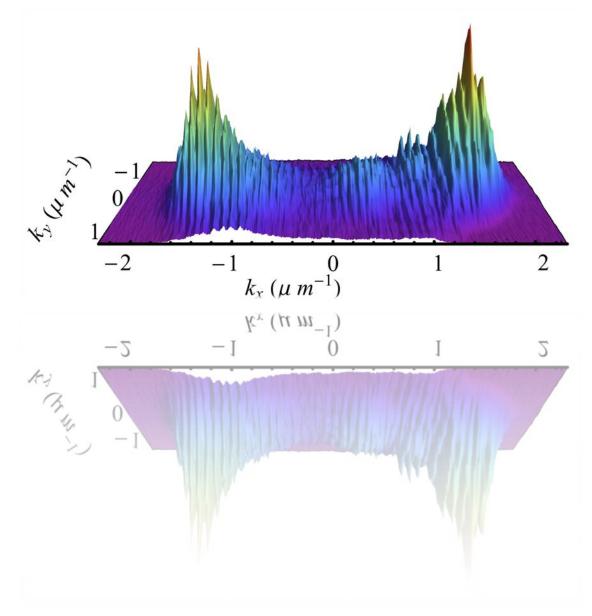


- Generation of ultrafast-propagating condensed polariton wave trains in quasi-1D microcavities → devices
- Transistor switch
- AND optical gate





Thank you very much...



...Funding

 ✓ Spanish MEC MAT2011-22997 & MAT2014-53119-C2-1-R
 ✓ CAM (S-2009/ESP-1503)
 ✓ FP7 ITN's "Clermont4" (235114)
 ✓ "Spin-optronics" (237252)
 ✓ INDEX (289968)